

# mSATA 3TE7 Series

## with Innodisk NAND

**Customer:** \_\_\_\_\_

**Customer**

**Part**

**Number:** \_\_\_\_\_

**Innodisk**

**Part**

**Number:** \_\_\_\_\_

**Innodisk**

**Model Name:** \_\_\_\_\_

**Date:** \_\_\_\_\_

Innodisk Approver	Customer Approver

**Features:**

- SATA III
- Innodisk 3D TLC NAND
- mSATA
- Standard temperature
- iPower Guard
- iData Guard
- Dynamic Thermal Management
- Direct Write

**Power Requirements:**

Input Voltage:	3.3V±5%
Max Operating Wattage:	2.2W
Idle Wattage:	0.8W

**Reliability:**

Capacity	TBW(Client)	DWPD(Client)
64GB	75	1.09
128GB	150	1.09
256GB	300	1.09
512GB	600	1.09
1TB	1200	1.09
2TB	2400	1.09

Data Retention	10 Years
Warranty	3 Years

For warranty details, please refer to:

[https://www.innodisk.com/en/support\\_and\\_service/warranty](https://www.innodisk.com/en/support_and_service/warranty)

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## REVISION HISTORY

Revision	Description	Date
1.0	Official Release	Aug., 2020
1.1	Update 1TB & 2TB Model	Sep., 2020
1.2	Combine 64 layers & 96 layers Power and Performance	Jan., 2021
1.3	Add Industrial Grade solution	Jan., 2021
2.0	Add 112 layers 3D TLC information	Jan., 2022
2.1	Update LBA	Feb., 2022
2.2	Remove EOL Products	Nov., 2023
2.3	Update Boot Up Power Consumption	Dec., 2023
2.4	Update Performance Remove EOL Products	Aug., 2024

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# 1. Product Overview

## 1.1 Introduction of Innodisk mSATA 3TE7

Innodisk mSATA 3TE7 is compliant with JEDEC MO-300 standard, supporting SATA III interface (6.0Gb/s). mSATA 3TE7 is capable of providing excellent performance with its 4 Channel 8 CE controller architecture with cost effectiveness in mind. In addition, through vigorous verification and with industrial-oriented Innodisk features, Innodisk mSATA 3TE7 is suitable for all fields of industrial application.

With Innodisk L<sup>3</sup> FW architecture, combining our signature 4K mapping algorithm L<sup>2</sup> FW architecture with powerful LDPC technology, 3TE7 series has outstanding high IOPS, better data integrity and extended lifespan through reducing the bad block number happening.

## 1.2 Product View and Models

Innodisk mSATA 3TE7 is available in follow capacities within 3D NAND flash ICs.

[mSATA 3TE7 64GB](#)    [mSATA 3TE7 256GB](#)    [mSATA 3TE7 1TB](#)

[mSATA 3TE7 128GB](#)    [mSATA 3TE7 512GB](#)    [mSATA 3TE7 2TB](#)



**Figure 1: Innodisk mSATA 3TE7**

## 1.3 SATA Interface

Innodisk mSATA 3TE7 supports SATA III(6.0Gb/s) interface, and compliant with SATA I (1.5Gb/s) and SATA II(3.0Gb/s).

## 2. Product Specifications

### 2.1 Capacity and Device Parameters

mSATA 3TE7 device parameters are shown in Table 1.

**Table 1: Device parameters**

Capacity	LBA	Cylinders	Heads	Sectors	User Capacity(GB)
64GB	107463888	16383	16	63	51.2
128GB	234441648	16383	16	63	111.8
256GB	468862128	16383	16	63	223.6
512GB	937703088	16383	16	63	447.1
1TB	1875385008	16383	16	63	894.3
2TB	3750748848	16383	16	63	1788.5

### 2.2 Performance

Burst Transfer Rate: 6.0Gbps

**Table 2: Performance – 112 Layers 3D TLC**

Capacity	Unit	64GB	128GB	256GB (4CH)	256GB (2CH)	512GB	1TB	2TB
Sequential** Read (Q32T1)	MB/s	260	430	550	420	560	550	550
Sequential** Write (Q32T1)		130	260	480	260	490	500	500
Sustained Sequential Read (Avg.)***		210	340	410	320	410	410	420
Sustained Sequential Write (Avg.)***		40	70	150	70	140	270	290
4KB Random** Read (QD32)	IOPS	20,000	36,000	71,000	35,000	68,000	85,000	86,000
4KB Random** Write (QD32)		10,000	20,000	39,000	26,000	48,000	74,000	74,000

Note: \* Performance results are tested in Room Temperature with Out-of-Box devices and may vary depending on overall system setup. In addition, 3TE7 series adopt hybrid mode which enables SLC Cache followed by TLC direct write to strike balance between burst performance and steady overall stability.

Note: \*\* Performance results are based on CrystalDiskMark 6.0.2 with typical tolerance for range from 1% to 10%.

Note: \*\*\* Performance results are based on AIDA 64 with block size 1MB of Linear Write Test Item

## 2.3 Electrical Specifications

### 2.3.1 Power Requirement

**Table 3: Innodisk mSATA 3TE7 Power Requirement**

Item	Symbol	Rating	Unit
Input voltage	V <sub>IN</sub>	+3.3 DC +- 5%	V

### 2.3.2 Power Consumption

**Table 4: Typical Power Consumption**

Mode	Power Consumption (W)
Read (RMS)	1.7
Write (RMS)	2.2
Idle (RMS)	0.8
Boot Up	3.8

## 2.4 Environmental Specifications

### 2.4.1 Temperature Ranges

**Table 5: Temperature range for mSATA 3TE7**

Temperature	Range
Operating (Ta)	Standard Grade: 0°C to +70°C
Storage	-40°C to +85°C

### 2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

### 2.4.3 Shock and Vibration

**Table 6: Shock/Vibration Testing for mSATA 3TE7**

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27

### 2.4.4 Mean Time between Failures (MTBF)

The following table summarizes the MTBF prediction results for various mSATA 3TE7 configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.

- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

**Table 7: mSATA 3TE7 MTBF**

Product	Condition	MTBF (Hours)
Innodisk mSATA 3TE7	Telcordia SR-332 GB, 25°C	>3,000,000

## 2.5 CE and FCC Compatibility

mSATA 3TE7 conforms to CE and FCC requirements.

Reliability	Reference standards
Electrostatic Discharge (ESD)	EC 61000-4-2 ESD

## 2.6 RoHS Compliance

mSATA 3TE7 is fully compliant with RoHS directive.

## 2.7 Reliability

Parameter	Value	
Flash endurance	3,000 P/E cycles	
Error Correct Code	Support	
Data Retention	Under 40°C: 1 Year at NAND Life End	
<b>TBW* (Total Bytes Written)</b>	Units: TB	
Capacity	Sequential workload	Client workload
64GB	170	75
128GB	341	150
256GB	682	300
512GB	1364	600
1TB	2727	1200
2TB	5455	2400

\* Note:

1. Sequential: Mainly sequential write, tested by Vdbench.
2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)
3. Based on out-of-box performance.

## 2.8 Transfer Mode

mSATA 3TE7 support following transfer mode:

Serial ATA III 6.0Gbps

Serial ATA II 3.0Gbps

Serial ATA I 1.5Gbps

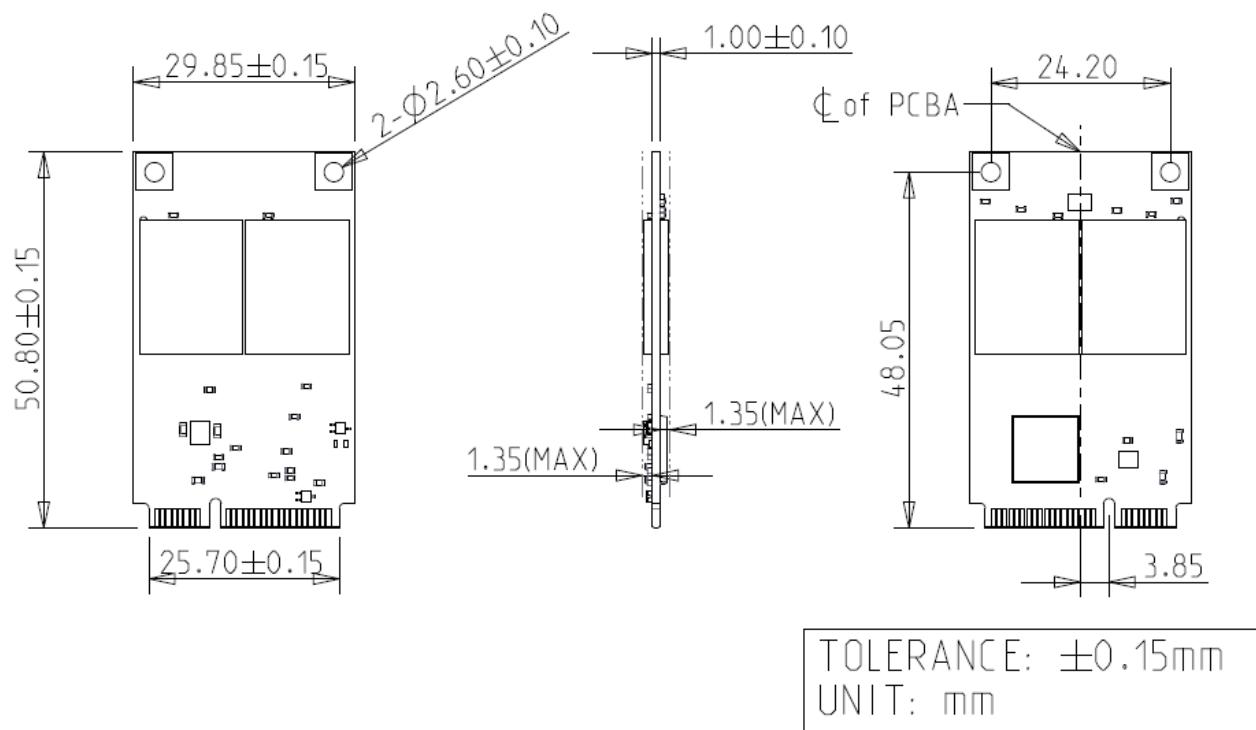
## 2.9 Pin Assignment

Innodisk mSATA 3TE7 uses a standard SATA pin-out. See following table for mSATA 3TE7 pin assignment.

**Table 8: Innodisk mSATA 3TE7 Pin Assignment**

Signal Name	Pin #	Pin #	Signal Name
GND	51	52	+3.3V
DAS	49	50	GND
NC	47	48	NC
NC	45	46	NC
NC	43	44	DEVSLP
+3.3V	41	42	NC
+3.3V	39	40	GND
GND	37	38	NC
GND	35	36	NC
RX+	33	34	GND
RX-	31	32	NC
GND	29	30	NC
GND	27	28	NC
TX-	25	26	GND
TX+	23	24	+3.3V
GND	21	22	NC
NC	19	20	NC
NC	17	18	GND
<hr/>			
GND	15	16	NC
NC	13	14	NC
NC	11	12	NC
GND	9	10	NC
NC	7	8	NC
NC	5	6	NC
NC	3	4	GND
NC	1	2	+3.3V

## 2.10 Mechanical Dimensions



**Figure 2: Innodisk mSATA 3TE7 diagram**

## 2.11 Assembly Weight

An Innodisk mSATA 3TE7 within flash ICs, 2TB's weight is 7 grams approximately.

## 2.12 Seek Time

Innodisk mSATA 3TE7 is not a magnetic rotating design. There is no seek or rotational latency required.

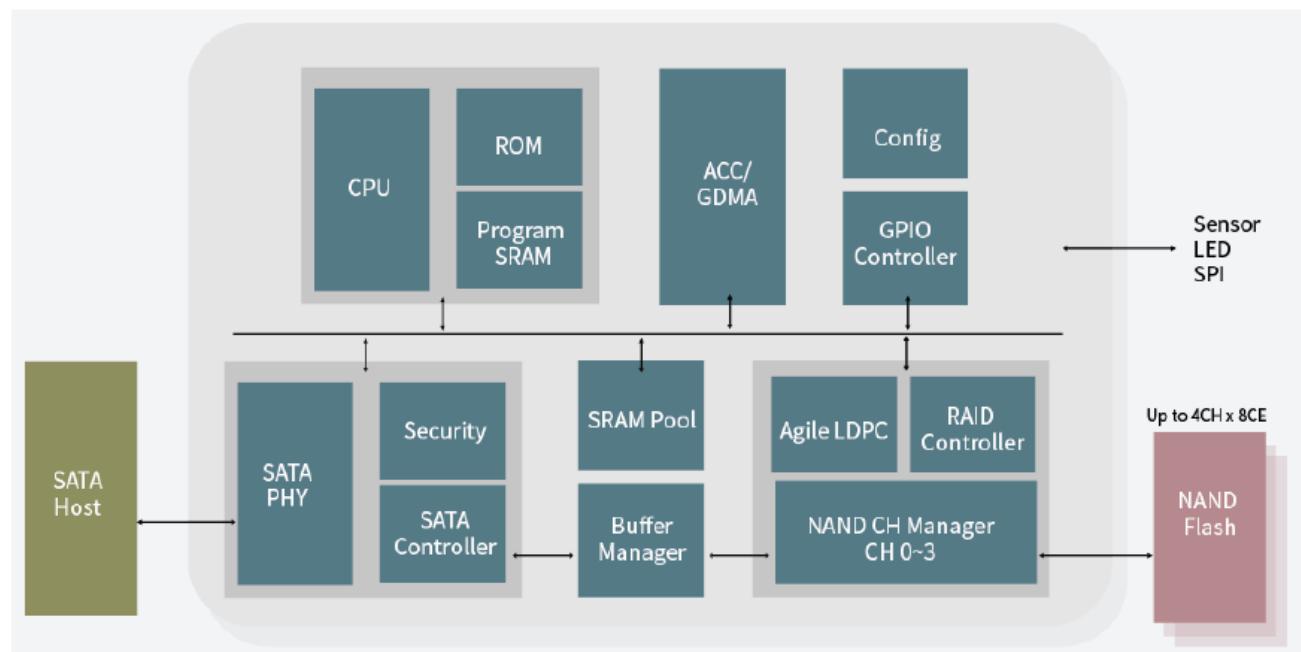
## 2.13 NAND Flash Memory

Innodisk mSATA 3TE7 uses 3D TLC NAND flash memory, with 3,000 program & erase cycles, which is non-volatility, high reliability and high-speed memory storage.

## 3. Theory of Operation

### 3.1 Overview

Figure 2 shows the operation of Innodisk mSATA 3TE7 from the system level, including the major hardware blocks.



**Figure 3: Innodisk mSATA 3TE7 Block Diagram**

Innodisk mSATA 3TE7 integrates a SATA III controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard ATA protocol. Communication with the flash device(s) occurs through the flash interface.

### 3.2 SATA III Controller

Innodisk mSATA 3TE7 is designed with a SATA III 6.0Gbps (Gen. 3) controller. The Serial ATA physical, link and transport layers are compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps/3.0Gbps/6.0Gbps data rate). The controller has 4 channels for flash interface.

### 3.3 Error Detection and Correction

Innodisk mSATA 3TE7 is designed with hardware LDPC ECC engine with hard-decision and Soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting Performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

### 3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk mSATA 3TE7 uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

### 3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

### 3.6 iData Guard

iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

### 3.7 Garbage Collection

Garbage collection is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

### 3.8 Trim

The Trim command is designed to enable the operating system to notify the SSD which pages no longer contain valid data due to erases either by the user or operating system itself. During a delete operation, the OS will mark the sectors as free for new data and send a Trim command to the SSD to mark them as not containing valid data. After that the SSD knows not to preserve the contents of the block when writing a page, resulting in less write amplification with fewer writes to the flash, higher write speed, and increased drive life.

### 3.9 iPower Guard

iPower Guard technology is a set of preventive measures that protect the SSD in an unstable power supply environment. This comprehensive package comprises safeguards for startup and shutdown to maintain device performance and ensure data integrity.

### 3.10 Die RAID

Die RAID is a controller function which leveraged user capacity to back up the data in NAND flash. Die RAID supported can ensure the user data in the NAND Flash more consistent in certain scenario. Innodisk mSATA 3TE7 series is default enable the Die RAID function for the industrial application.

### 3.11 SLC cache

**Table 9: mSATA 3TE7 SLC cache**

Capacity	64GB	128GB	256GB	512GB	1TB	2TB
SLC cache (GB)	3	3	5	9	18	36
SLC cache (%)	4.6	2.3	1.9	1.7	1.7	1.7

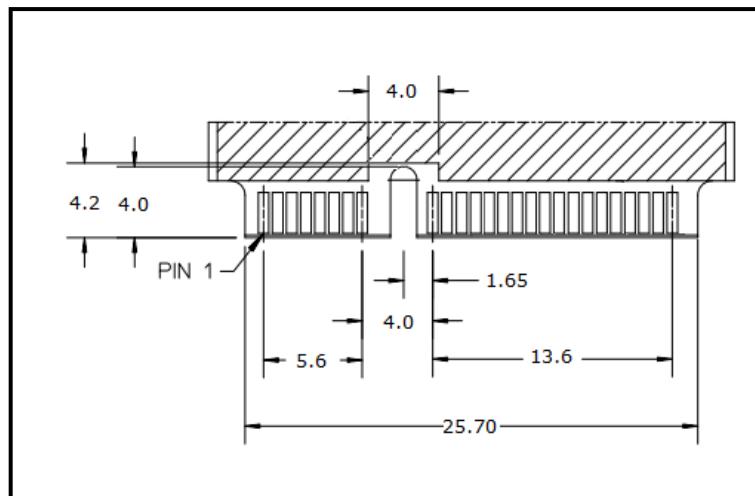
3TE7 series adopt hybrid mode which enables SLC Cache up to 3% of total user capacity by TLC direct write to strike balance between burst performance and steady overall stability.

### 3.12 Thermal Throttling

Thermal throttling is a protective mechanism designed to safeguard components from potential damage caused by excessive temperatures. When an SSD approaches a critical temperature threshold, Innodisk firmware activates the thermal throttling mechanism to regulate the SSD's temperature. Thermal throttling is crucial for SSDs since it prevents drive damage, which could otherwise result in data loss. However, it's worth noting that when thermal throttling is activated, read and write tasks may experience a reduction in speed.

## 4. Installation Requirements

### 4.1 mSATA 3TE7 Pin Directions



**Figure 4: Signal Segment and Power Segment**

### 4.2 Electrical Connections for mSATA 3TE7

A Serial ATA device may be either directly connected to a host or connected to a host through an adaptor card. The SATA interface has a separate connector for the power supply. Please refer to the pin description for further details.

### 4.3 Device Drive

No additional device drives are required. The Innodisk mSATA 3TE7 can be configured as a boot device.

## 5. SMART Feature Set

Innodisk 3TE7 series support the SMART command set and defines some vendor-specific data to report SMART attributes of SSD.

**Table 10: SMART command**

Value	Command	Value	Command
D0h	Read Data	D5h	Read Log
D1h	Read Attribute Threshold	D6h	Return Status
D2h	Enable/Disable Auto save	D8h	Enable SMART Operations
D3h	Save Attribute Values	D9h	Disable SMART Operations
D4h	Execute OFF-LINE Immediate	DAh	Return Status

### 5.1 SMART Attributes

Innodisk 3TE7 series SMART data attributes are listed in following table.

**Table 11: SMART attribute**

Attribute ID (hex)	Value	Raw Attribute Value							Rsv	Attribute Name
05	X	LSB	MSB	00	00	00	00	00	00	Later Bad
09	LSB	LSB	MSB	00	00	00	00	00	00	Power-On hours Count
0C	LSB	LSB	MSB	00	00	00	00	00	00	Drive Power Cycle Count
A3	X	LSB			MSB	00	00	00	00	Total Bad Block Count
A5	LSB	LSB			MSB	00	00	00	00	Max Erase count
A7	LSB	LSB			MSB	00	00	00	00	Avg Erase count
A9	LSB	LSB	00	00	00	00	00	00	00	Device Life
AA	X	LSB	MSB	00	00	00	00	00	00	Spare Block Count
AB	LSB	LSB	MSB	00	00	00	00	00	00	Program fail count
AC	LSB	LSB	MSB	00	00	00	00	00	00	Erase fail count
C0	LSB	LSB	MSB	00	00	00	00	00	00	Unexpected Power Loss Count
C2	LSB			MIN		MAX	00	00	00	Temperature
E5		ID 0	ID 1	ID 2	ID 3	ID 4	ID 5			Flash ID

EB			<b>MSB</b>	<b>LSB</b>	<b>MSB</b>	<b>LSB</b>	<b>MSB</b>	<b>LSB</b>	Later bad block info ( <b>Read</b> / <b>Write</b> / <b>Erase</b> )
F1	00	LSB			MSB	00	00	00	Total LBA written(LBA=32MB)
F2	00	LSB			MSB	00	00	00	Total LBA read(LBA=32MB)

## 6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
	<b>D</b>	<b>E</b>	<b>M</b>	<b>S</b>	<b>R</b>	-	<b>C</b>	<b>1</b>	<b>2</b>	<b>D</b>	<b>K</b>	<b>1</b>	<b>K</b>	<b>C</b>	<b>A</b>	<b>Q</b>	<b>L</b>	-	<b>X</b>	<b>X</b>	<b>X</b>
<b>Definition</b>																					
<b>Code 1<sup>st</sup> (Disk)</b>											<b>Code 13<sup>th</sup> (Flash Mode)</b>										
D : Disk											K: 112 layers 3D TLC										
<b>Code 2<sup>nd</sup> (Feature Set)</b>											<b>Code 14<sup>th</sup> (Operation Temperature)</b>										
E: Embedded											C: Standard Grade (0°C ~ +70°C)										
<b>Code 3<sup>rd</sup>~ 5<sup>th</sup> (Form Factor)</b>																					
MSR: mSATA Regular											<b>Code 15<sup>th</sup> (Internal control)</b>										
											A: PCB version										
<b>Code 7<sup>th</sup> ~9<sup>th</sup> (Capacity)</b>																					
64G: 64GB											<b>Code 16<sup>th</sup> (Channel of data transfer)</b>										
A28: 128GB											S: Single Channel										
B56: 256GB											D: Dual Channels										
C12: 512GB											Q: Quad Channels										
01T: 1TB											<b>Code 17<sup>th</sup> (Flash Type)</b>										
02T: 2TB											L: Innodisk 3D TLC										
<b>Code 10th ~12th (Controller)</b>											<b>Code 19<sup>th</sup>~21<sup>th</sup> (Customized Code)</b>										
DK1: SATA 3TE7																					